

MC33680

Dual DC-DC Regulator for Electronic Organizer

The MC33680 is a dual DC-DC regulator designed for electronic organizer applications. Both regulators apply Pulse-Frequency-Modulation (PFM). The main step-up regulator output can be externally adjusted from 2.7V to 5V. An internal synchronous rectifier is used to ensure high efficiency (achieve 87%). The auxiliary regulator with a built-in power transistor can be configured to produce a wide range of positive voltage (can be used for LCD contrast voltage). This voltage can be adjusted from +5V to +25V by an external potentiometer.

The MC33680 has been designed for battery powered hand-held products. With the low start-up voltage from 1V and the low quiescent current (typical 35 μ A); the MC33680 is best suited to operate from 1 to 2 AA/ AAA cell. Moreover, supervisory functions such as low battery detection, CPU Power-Good signal, and back-up battery control, for lithium battery or supercap are also included in the chip.

FEATURES:

- Low Input Voltage, 1V up
- Low Quiescent Current in Standby Mode: 35 μ A typical
- PFM and Synchronous Rectification to ensure high efficiency (87% @60mA Load)
- Adjustable Main Output: +2.7V to +5V nominal 3.3V @ 100mA max, with 1.8V input
- Auxiliary Output Voltage: +5V to +25V +5V @ 25mA max, with 1.8V input +25V @ 15mA max, with 1.8V input
- Current Limit Protection
- Power-Good Signal with Programmable Delay
- Battery Low Detection
- Lithium Battery or Supercap Back-up
- 32-Pin LQFP Package

APPLICATIONS:

- Digital Organizer and Dictionary
- Dual Output Power Supply (For MPU, Logic, Memory, LCD)
- Handheld Battery Powered Device (1-2 AA/AAA cell)



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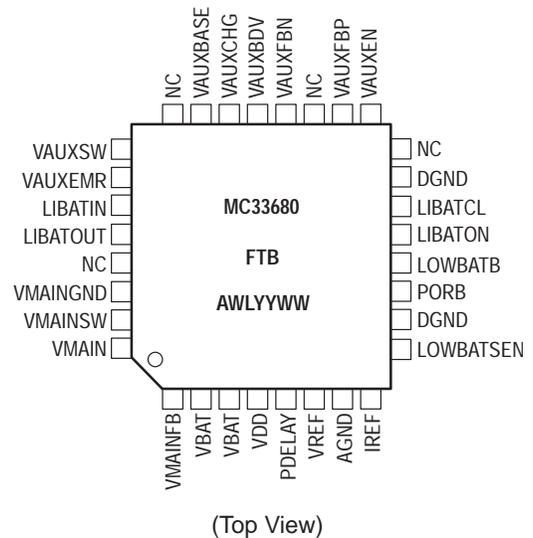
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32 1

32-LEAD LQFP
FTB SUFFIX
CASE 873A

PIN CONNECTIONS & DEVICE MARKING



ORDERING INFORMATION

Device	Package	Shipping
MC33680FTB	LQFP	1250 Tray / Drypack
MC33680FTBR2	LQFP	1800 / Tape & Reel

TIMING DIAGRAMS

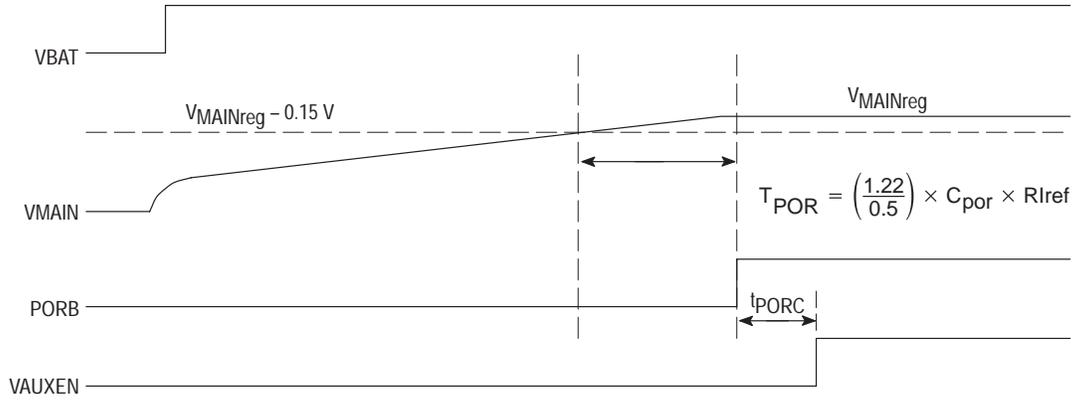


Figure 2. Startup Timing

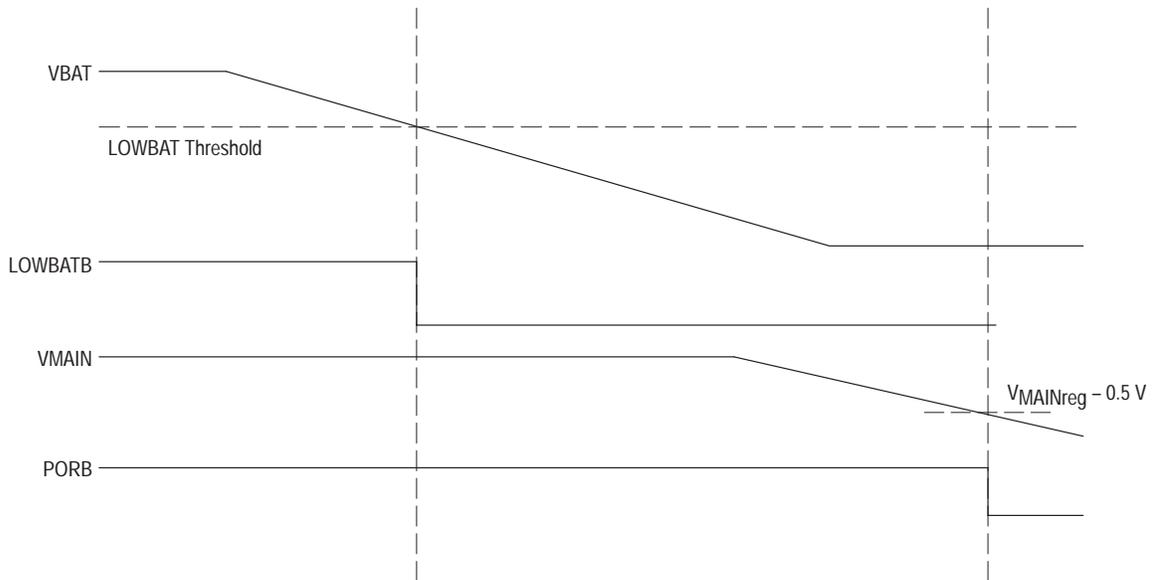


Figure 3. Power Down Timing

MC33680

PIN FUNCTION DESCRIPTION

Pin No.	Function	Type/Direction	Description
1	VMAINFB	Analog / Input	Feedback pin for VMAIN
2	VBAT	Power	Main battery supply
3	VBAT	Power	Main battery supply
4	VDD	Analog / Output	Connect to decoupling capacitor for internal logic supply
5	PDELAY	Analog / Input	Capacitor connection for defining Power-On signal delay
6	VREF	Analog / Output	Bandgap Reference output voltage. Nominal voltage is 1.25V
7	AGND	Analog Ground	
8	IREF	Analog / Input	Resistor connection for defining internal current bias and PDELAY current
9	LOWBATSEN	Analog / Input	Resistive network connection for defining low battery detect threshold
10	DGND	Digital Ground	
11	PORB	CMOS / Output	Active LOW Power-On reset signal
12	LOWBATB	CMOS / Output	Active LOW low battery detect output
13	LIBATON	CMOS / Input	microprocessor control signal for Lithium battery backup switch, the switch is ON when LIBATON=HIGH and LIBATCL=HIGH
14	LIBATCL	CMOS / Input	microprocessor control signal for Lithium battery backup switch, if it is HIGH, the switch is controlled by LIBATON, otherwise, controlled by internal logic
15	DGND	Digital Ground	
16	NC		no connection
17	VAUXEN	CMOS / Input	VAUX enable, Active high
18	VAUXFBP	Analog / Input	Feedback pin for VAUX
19	NC		no connection
20	VAUXFBN	Analog / Input	Feedback pin for VAUX
21	VAUXBDV	Power	VAUX BJT base drive circuit power supply
22	VAUXCHG	Analog / Output	test pin
23	VAUXBASE	Analog / Output	test pin
24	NC		no connection
25	VAUXSW	Analog / Output	Collector output of the VAUX power BJT
26	VAUXEMR	Analog / Output	Emitter output of the VAUX power BJT
27	LIBATIN	Analog / Input	Lithium battery input for backup purposes
28	LIBATOUT	Analog / Output	Lithium battery output
29	NC		no connection
30	VMAINGND	Power Ground	Ground for VMAIN low side switch
31	VMAINSW	Analog / Input	VMAIN inductor connection
32	VMAIN	Analog / Output	VMAIN output

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ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise noted.)

Parameter	Symbol	Min	Max	Unit
Power Supply Voltage	V _{BAT}	-0.3	7.0	Vdc
Digital Pin Voltage	V _{digital}	-0.3	7.0	Vdc
General Analog Pin Voltage	V _{analog}	-0.3	7.0	Vdc
Pin VAUXSW to Pin VAUXEMR Voltage (Continuous)	V _{AUXCE}	-0.3	30	Vdc
Pin VMAINSW to Pin VMAIN Voltage (Continuous)	V _{syn}		0.3	Vdc
Operating Junction Temperature	T _j (max)		150	°C
Ambient Operating Temperature	T _a	0	70	°C
Storage Temperature	T _{stg}	-50	150	°C

STATIC ELECTRICAL CHARACTERISTICS (Circuit of Figure 1, V_P = 1.8V, I_{load} = 0 mA, T_A = 0 to 70°C unless otherwise noted.)

Rating	Symbol	Min	Typ	Max	Unit
Operating Supply Voltage ¹	V _{BAT}	1.0			V
VMAIN output voltage	V _{main}	3.1	3.3	3.5	V
VMAIN output voltage range ²	V _{main_range}	2.7		5.0	V
VMAIN output current ³	I _{3.3_1.8}			200	mA
VMAIN maximum switching frequency ⁴	Freq _{max_VM}			100	kHz
VMAIN peak coil static current limit	I _{LIM_VM}	0.85	1.0	1.15	A
VAUX output voltage range	V _{AUX_range}	5.0		25	V
VAUX maximum switching frequency	Freq _{max_VL}			120	kHz
VAUX peak coil static current limit	I _{LIM_VL}		1.0		A
Quiescent Supply Current at Standby Mode ⁵	I _{qstandby}		35	60	μA
Reference Voltage @ no load	V _{refno_load}	1.16	1.22	1.28	V
Battery Low Detect lower hysteresis threshold ⁶	V _{LOBAT_L}	0.8	0.85	0.9	V
Battery Low Detect upper hysteresis threshold	V _{LOBAT_H}	1.05	1.1	1.15	V
PDELAY Pin output charging current	I _{chgPDELAY}	0.8	1.0	1.2	μA
PDELAY Pin voltage threshold	V _{thPDELAY}	1.16	1.22	1.28	V

NOTE: 1. Output current capability is reduced with supply voltage due to decreased energy transfer. The supply voltage must not be higher than VMAIN+0.6V to ensure boost operation. Max Start-up loading is typically 1V at 400 μA, 1.8V at 4.4 mA, and 2.2V at 88 mA.

NOTE: 2. Output voltage can be adjusted by external resistor to the VMAINFB pin.

NOTE: 3. At V_{BAT} = 1.8V, output current capability increases with V_{BAT}.

NOTE: 4. Only when current limit is not reached.

NOTE: 5. This is average current consumed by the IC from VDD, which is low-pass filtered from VMAIN, when only VMAIN is enabled and at no loading.

NOTE: 6. This is the minimum of "LOWBATB" threshold for battery voltage, the threshold can be increased by external resistor divider from "VBAT" to "LOWBATSEN".

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DYNAMIC ELECTRICAL CHARACTERISTICS (Refer to TIMING DIAGRAMS, $T_A = 0$ to 70°C unless otherwise noted.)

Rating	Symbol	Min	Typ	Max	Unit
Minimum PORB to Control delay	t_{PORC}			500	nS

Figure 4. Efficiency of VMAIN versus Output Current (VMAIN = 3.3 V, L = 33 μH , Various V_{IN})

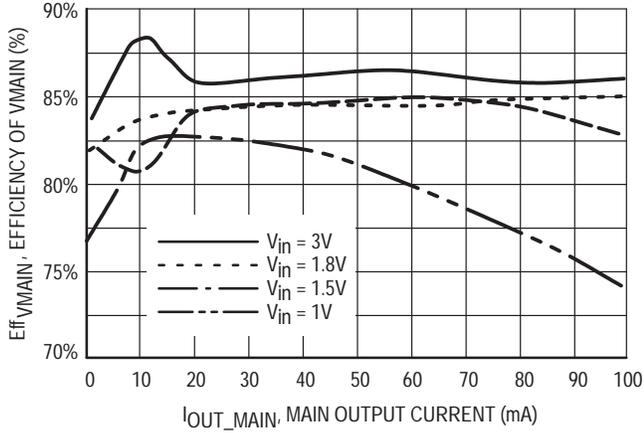


Figure 5. Efficiency of VMAIN versus Input Voltage (VMAIN = 3.3 V, L1 = 33 μH , Various I_{OUT})

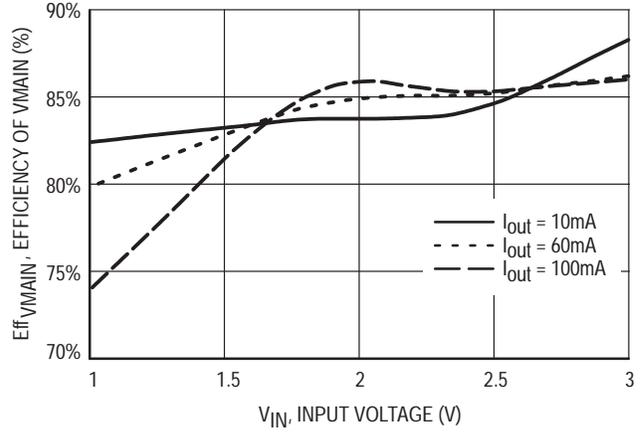


Figure 6. Efficiency of VAUX versus Output Current (VAUX = 25 V, L2 = 33 μH , Various V_{IN})

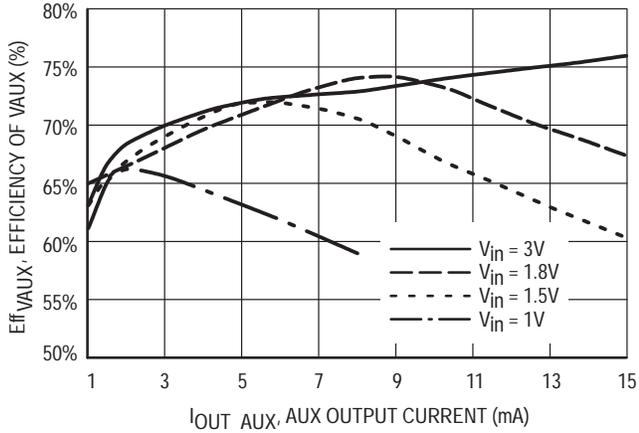


Figure 7. Efficiency of VAUX versus Input Voltage (VAUX = 25 V, L2 = 33 μH , Various I_{OUT})

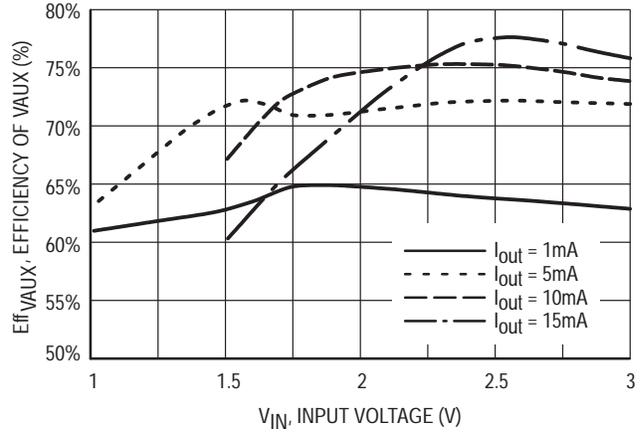


Figure 8. Efficiency of VAUX versus Output Current (VAUX = 20 V, L2 = 33 uH, Various VIN)

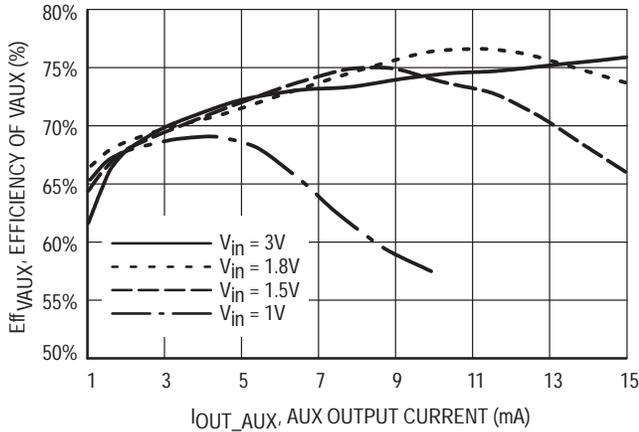


Figure 9. Efficiency of VAUX versus Input Voltage (VAUX = 20 V, L2 = 33 uH, Various IOUT)

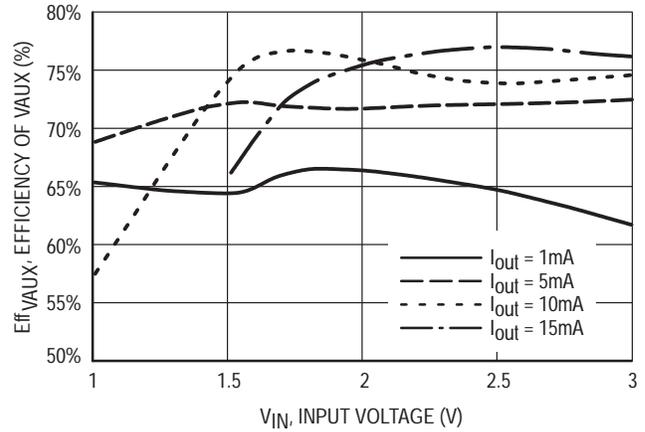


Figure 10. Efficiency of VAUX versus Output Current (VAUX = 5 V, L2 = 82 uH, Various VIN)

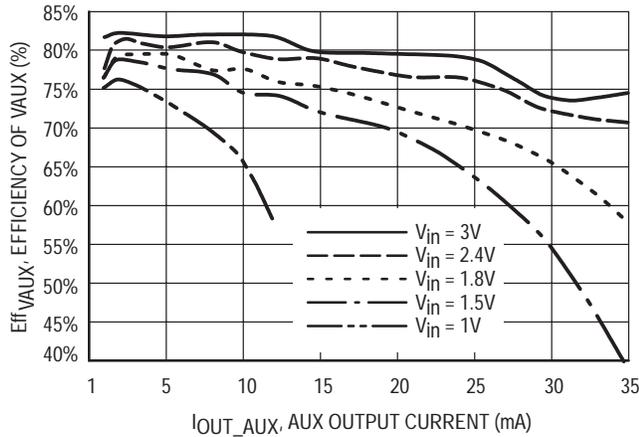


Figure 11. Efficiency of VAUX versus Input Voltage (VAUX = 5 V, L2 = 82 uH, Various IOUT)

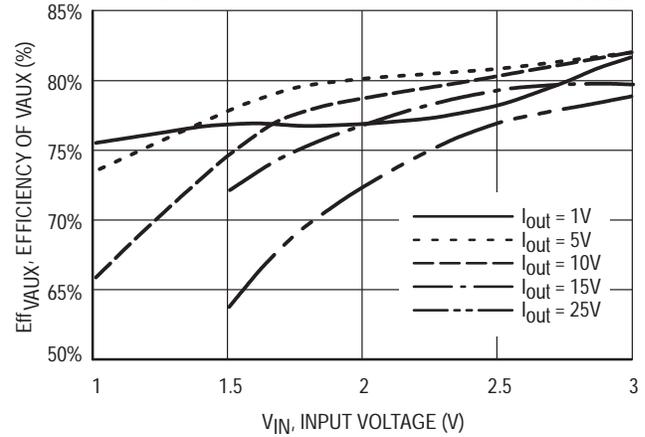
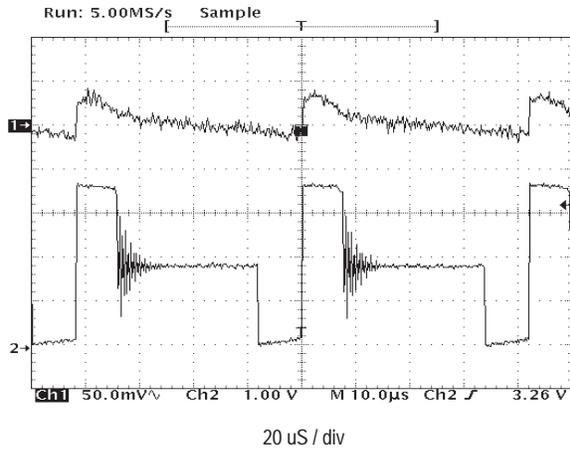
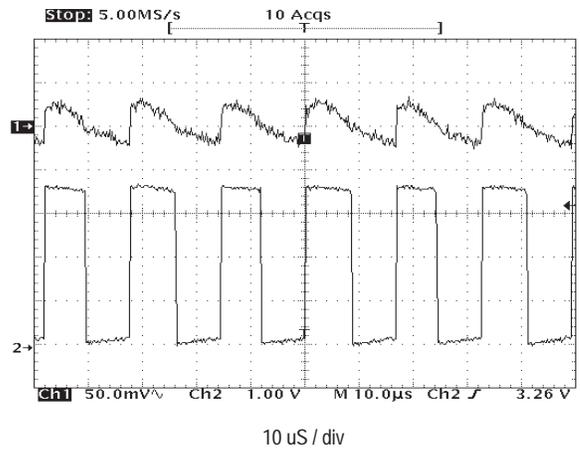


Figure 12. VMAIN Output Ripple (Medium Load)



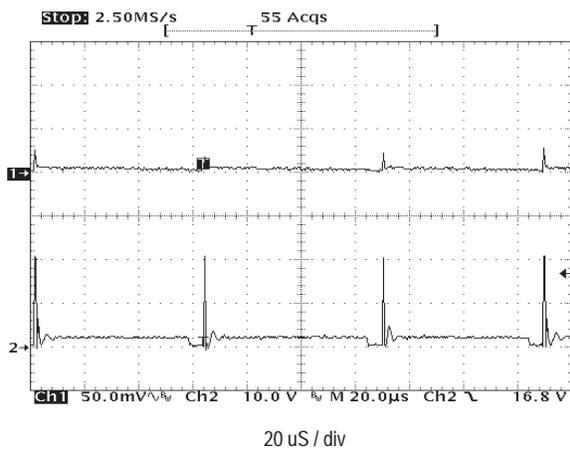
1: VMAIN = 3.3 V (50 mV/div, AC COUPLED)
2: Voltage at VMAINSW (1 V/div)

Figure 13. VMAIN Output Ripple (Heavy Load)



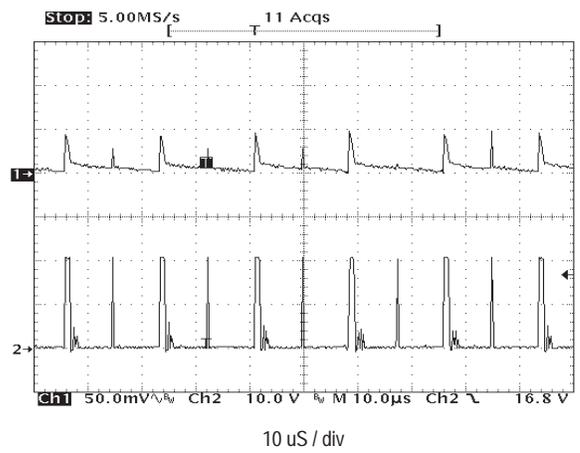
1: VMAIN = 3.3 V (50 mV/div, AC COUPLED)
2: Voltage at VMAINSW (1 V/div)

Figure 14. VAUX Output Ripple (Medium Load)



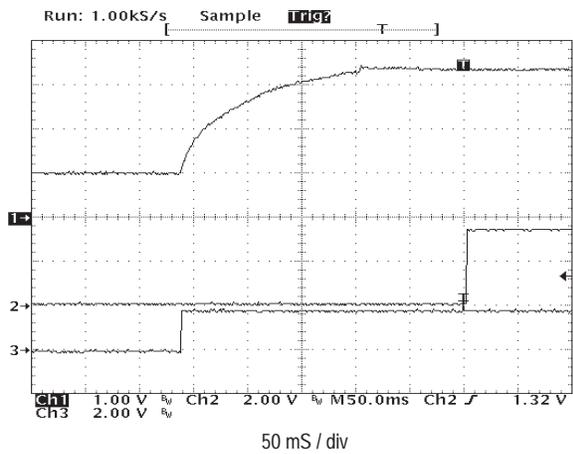
1: VAUX = 20 V (50 mV/div, AC COUPLED)
2: Voltage at VAUXSW (10 V/div)

Figure 15. VAUX Output Ripple (Heavy Load)



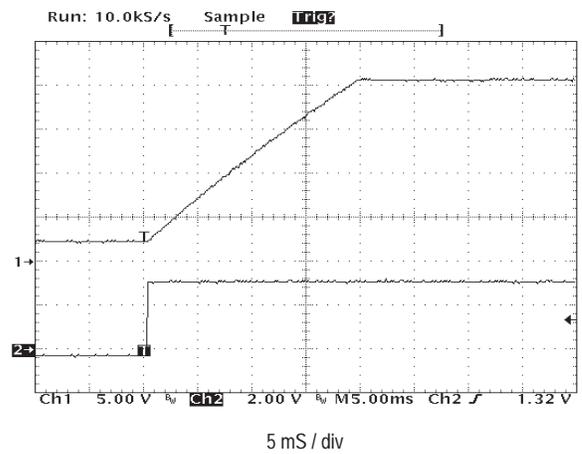
1: VAUX = 20 V (50 mV/div, AC COUPLED)
2: Voltage at VAUXSW (10 V/div)

Figure 16. VMAIN Startup and Power-Good Signal



1: VMAIN from 1 V to 3.3 V (1 V/div)
2: Voltage of PORB (2 V/div)
3: Voltage of ENABLE (2 V/div)

Figure 17. VAUX Startup



1: VAUX from 1.8 V to 20 V (5 V/div)
2: VAUXEN (2 V/div)

DETAILED OPERATING DESCRIPTION

General

The MC33680 is a dual DC–DC regulator designed for electronic organizer applications. Both regulators apply Pulse–Frequency–Modulation (PFM). The main boost regulator output can be externally adjusted from 2.7V to 5V. An internal synchronous rectifier is used to ensure high efficiency (achieve 87%). The auxiliary regulator with a built–in power transistor can be configured to produce a wide range of positive voltage (can be used for LCD contrast voltage). This voltage can be adjusted from +5V to +25V by an external potentiometer.

The MC33680 has been designed for battery powered hand–held products. With the low start–up voltage from 1V and the low quiescent current (typical 35 μ A), the MC33680 is best suited to operate from 1 to 2 AA/ AAA cell. Moreover, supervisory functions such as low battery detection, CPU Power–Good signal, and back–up battery control, are also included in the chip. It makes the MC33680 the best one–chip power management solution for applications such as electronic organizers and PDAs.

Pulse Frequency Modulation (PFM)

Both regulators apply PFM. With this switching scheme, every cycle is started as the feedback voltage is lower than the internal reference. This is normally performed by internal comparator. As cycle starts, Low–Side switch (i.e. M1 in Figure 1) is turned ON for a fixed ON time duration (namely, T_{ON}) unless current limit comparator senses coil current has reached its preset limit. In the latter case, M1 is OFF instantly. So T_{ON} is defined as the maximum ON time of M1. When M1 is ON, coil current ramps up, so energy is being stored inside the coil. At the moment just after M1 is OFF, the Synchronous Rectifier (i.e. M2 in Figure 1) or any rectification device (such as Schottky Diode of Auxiliary Regulator) is turned ON to direct coil current to charge up the output bulk capacitor. Provided that coil current limit is not reached, every switching cycle delivers fixed amount of energy to the bulk capacitor. For higher loading, a larger amount of energy (Charge) is withdrawn from the bulk capacitor, and a larger amount of Charge is then supplied to the bulk capacitor to regulate output voltage. This implies switching frequency is increased; and vice–versa.

Main Regulator

Figure 18 shows the simplified block diagram of Main Regulator. Notice that precise bias current I_{ref} is generated by a VI converter and external resistor R_{Iref} , where

$$I_{ref} = \frac{0.5}{R_{Iref}} \quad (\text{A})$$

This bias current is used for all internal current bias as well as setting V_{MAIN} value. For the latter application, I_{ref} is doubled and fed as current sink at Pin 1. With external resistor R_{MAINb} tied from Pin1 to Pin32, a constant voltage level shift is generated in between the two pins. In close–loop operation, voltage at Pin 1 (i.e. Output feedback voltage) is needed to be regulated at the internal reference voltage level, 1.22V. Therefore, the delta voltage across Pin 1 and Pin 32 which can be adjusted by R_{MAINb} determines the Main Output voltage. If the feedback voltage drops below 1.22V, internal comparator sets switching cycle to start. So, V_{MAIN} can be calculated as follows.

$$V_{MAIN} = 1.22 + \frac{R_{MAINb}}{R_{Iref}} \quad (\text{V})$$

From the above equation, although V_{MAIN} can be adjusted by R_{MAINb} and R_{Iref} ratio, for setting V_{MAIN} , it is suggested, by changing R_{MAINb} value with R_{Iref} kept at 480K. Since changing R_{Iref} will alter internal bias current which will affect timing functions of Max ON time (T_{ON1}) and Min OFF time (T_{OFF1}). Their relationships are as follows;

$$T_{ON1} = 1.7 \times 10^{-11} \times R_{Iref} \quad (\text{S})$$

$$T_{OFF1} = 6.4 \times 10^{-12} \times R_{Iref} \quad (\text{S})$$

Continuous Conduction Mode and Discontinuous Conduction Mode

In Figure 19, regulator is operating at Continuous Conduction Mode. A switching cycle is started as the output feedback voltage drops below internal voltage reference V_{REF} . At that instant, the coil current is not yet zero, and it starts to ramp up for the next cycle. As the coil current ramps up, loading makes the output voltage to decrease as the energy supply path to the output bulk capacitor is disconnected. After T_{ON} elapses, M1 is OFF, M2 is ON, energy is pumped to the bulk capacitor. Output voltage is increased as excessive charge is pumped in, then it is decreased after the coil current drops below the loading. Notice the abrupt spike of output voltage is due to ESR of the bulk capacitor. Feedback voltage can be resistor–divided down or level–shift down from the output voltage. As this feedback voltage drops below V_{REF} , next switching cycle starts.

DETAILED OPERATING DESCRIPTION (Cont'd)

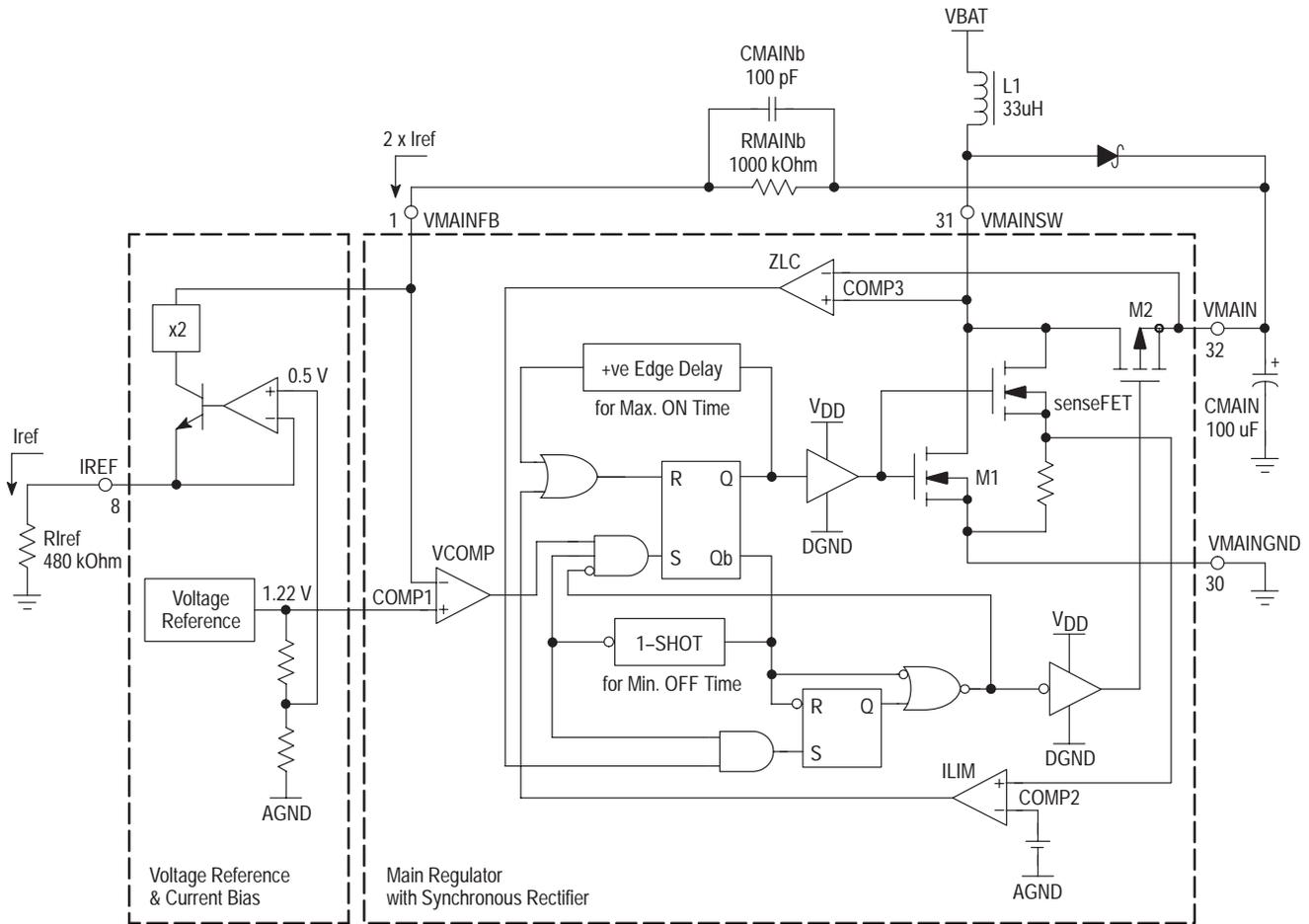


Figure 18. Simplified Block Diagram of Main Regulator

In Figure 20, regulator is operating at Discontinuous Conduction Mode, waveforms are similar to those of Figure 19. However, coil current drops to zero before next switching cycle starts.

To estimate conduction mode, below equation can be used.

$$I_{room} = \frac{\eta \times T_{ON} \times Vin^2}{2 \times L \times Vout} - I_{LOAD}$$

where, η is efficiency, refer to Figure 4

if $I_{room} > 0$, the regulator is at Discontinuous Conduction mode

if $I_{room} = 0$, the regulator is at Critical Conduction mode where coil current just drops to zero and next cycle starts.

if $I_{room} < 0$, the regulator is at Continuous Conduction mode

For Continuous Conduction mode, provided that current limit is not reached,

$$T_{SW} = \frac{T_{ON}}{1 - \eta \left(\frac{Vin}{Vout} \right)} \quad (S);$$

$$I_{pk} = \frac{I_{LOAD}}{1 - \left(\frac{T_{ON}}{T_{SW}} \right)} + \frac{Vin \times T_{ON}}{2 \times L} \quad (A)$$

For Discontinuous Conduction mode, provided that current limit is not reached,

$$T_{SW} = \frac{Vin \cdot T_{ON}^2}{2 \cdot L \cdot I_{LOAD} \cdot \left(\frac{Vout}{\eta \cdot Vin} - 1 \right)} \quad (S);$$

$$I_{pk} = \frac{Vin}{L} \cdot T_{ON} \quad (A)$$

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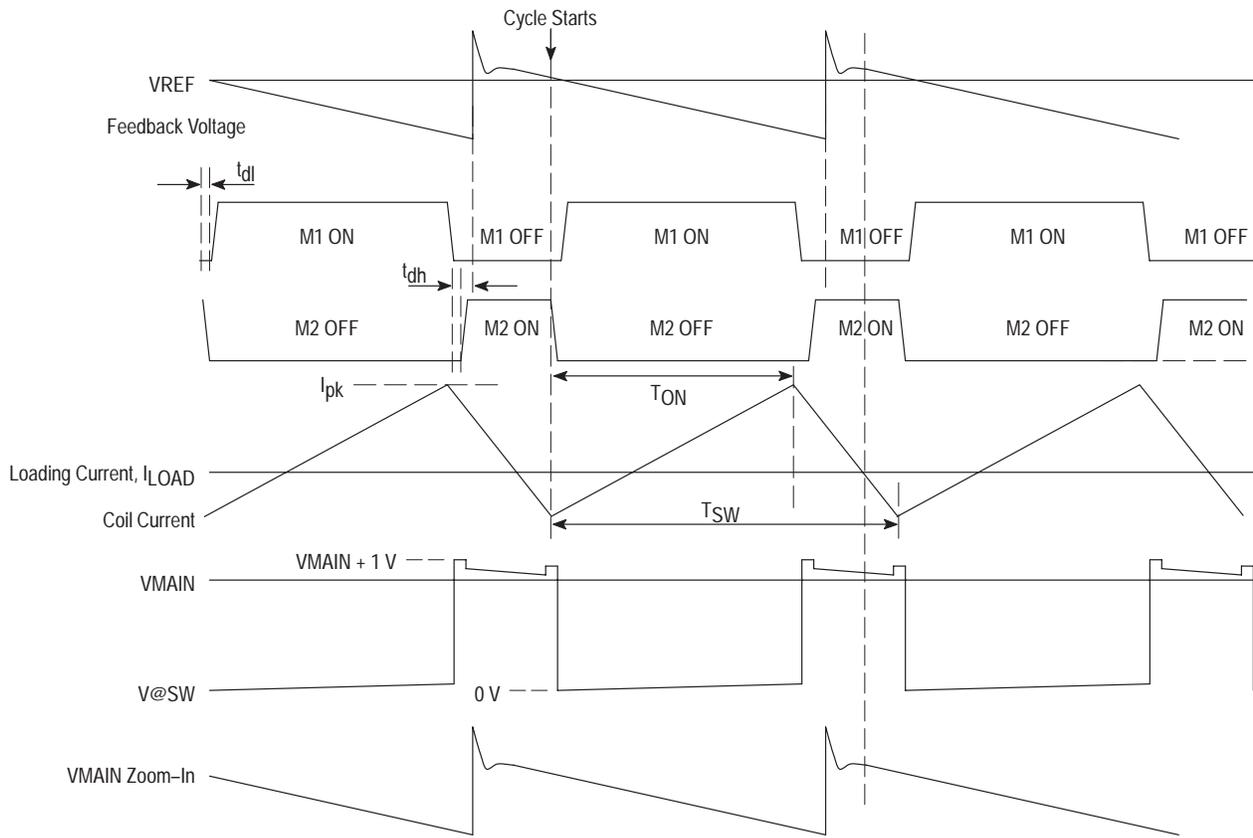


Figure 19. Waveforms of Continuous Conduction Mode

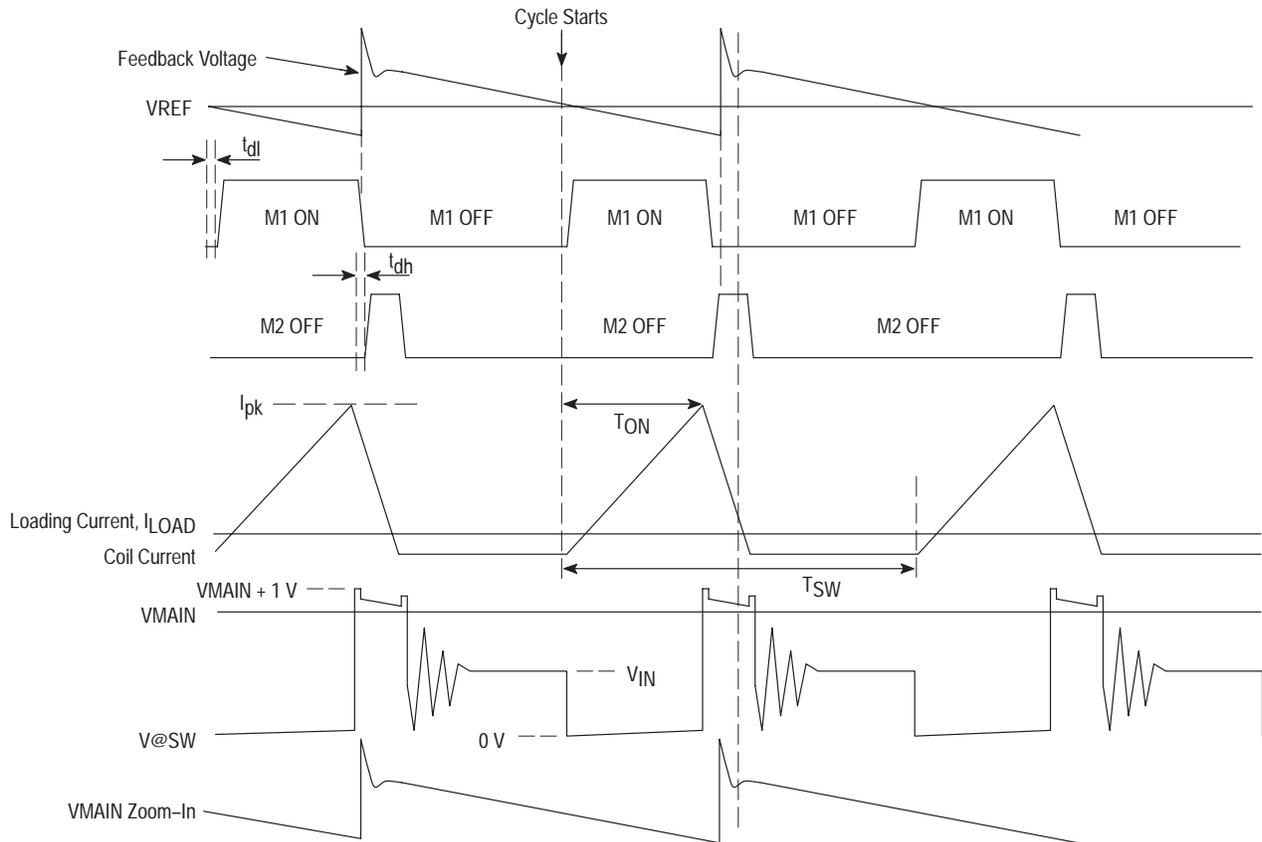


Figure 20. Waveforms of Discontinuous Conduction Mode

DETAILED OPERATING DESCRIPTION (Cont'd)

Current Limit for Both regulators

From Figure 18 and Figure 21, sense devices (senseFET or senseBJT) are applied to sample coil current as the low-side switch is ON. With that sample current flowing through a sense resistor, sense-voltage is developed. Threshold detector (COMP2 in both Figures) detects whether the sense-voltage is higher than preset level. If it happens, detector output reset the flip-flop to switch OFF low-side switch, and the switch can only be ON as next cycle starts.

Power-Good Signal

During the startup period (see Figure 2), the internal startup circuitry is enabled to pump up VMAIN to a certain voltage level, which is the user-defined VMAIN output level minus an offset of 0.15V. The internal Power-Good signal is then enabled to activate the main regulator and conditionally the auxiliary regulator. Meanwhile, the startup circuitry will be shut down. The Power-Good signal block also starts to charge up the external capacitor tied from Pin PDELAY to ground with precise constant current. As the Pin PDELAY's voltage reaches an internal set threshold, Pin PORB will go HIGH to awake the microprocessor. This delay is stated as follows;

$$T_{POR} = \left(\frac{1.22}{0.5}\right) \times C_{por} \times R_{lref} \text{ (S)}$$

From Figure 3, if, by any chance, VMAIN is dropped below the user-defined VMAIN output level minus 0.5V, PORB will go LOW to indicate the OUTPUT LOW situation. And, the IC will continue to function until the VMAIN is dropped below 2V.

Low-Battery-Detect

The Low-Battery-Detect block is actually a voltage comparator. Pin LOWBAT is LOW, if the voltage of external Pin LOWBATSEN is lower than 0.85V. The IC will neglect this warning signal. Pin LOWBAT will become HIGH, if the voltage of external Pin LOWBATSEN is recovered to more than 1.1V. From Figure 1, with external resistors RLBa and RLbB, thresholds of Low-Battery-Detect can be adjusted based on the equations below.

$$V_{LOBAThigh} = 1.1 \times \left(1 + \frac{R_{LBa}}{R_{LBb}}\right) \text{ (V)}$$

$$V_{LOBATlow} = 0.85 \times \left(1 + \frac{R_{LBa}}{R_{LBb}}\right) \text{ (V)}$$

Lithium-Battery backup

The backup conduction path which is provided by an internal power switch (typ. 13 Ohm) can be controlled by internal logic or microprocessor.

If LIBATCL is LOW, the switch, which is then controlled by internal logic, is ON when the battery is removed and VMAIN is dropped below LIBATIN by more than 100mV, and returns OFF when the battery is plugged back in.

If LIBATCL is HIGH, the switch is controlled by microprocessor through LIBATON. The truth table is shown in Figure 22.

Efficiency and Output Ripple

For both regulators, when large values are used for feedback resistors (> 50kOhm), stray capacitance of pin 1 (VMAINFB) and pin 20 (VAUXFBN) can add "lag" to the feedback response, destabilizing the regulator and creating a larger ripple at the output. From Figure 1, ripple of Main and AUX regulator can be reduced by capacitors in parallel with RMAINb, RAUXa and RAUXb ranging from 100pF to 100nF respectively. Reducing the ripple is also with improving efficiency, system designers are recommended to do experiments on capacitance values based on the PCB design.

Bypass Capacitors

If the metal lead from battery to coils are long, its stray resistance can put additional power loss to the system as AC current is being conducted. In that case, bypass capacitors should be placed closely to the coil, and connected from VBAT to ground. This reduces AC component of coil current passing through the long metal lead, thus minimizing that portion of power loss.

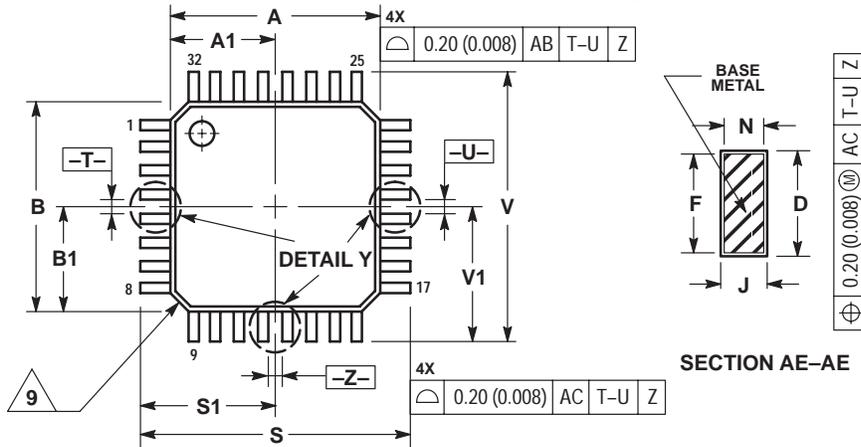
LIBATCL	LIBATON	Action
0	X	The switch is ON when the battery is removed and VMAIN is dropped below LIBATIN by more than 100mV; The switch is OFF when the battery is plugged in.
1	0	The switch is OFF
1	1	The switch is ON

Figure 22. Lithium Battery Backup Control Truth Table

MC33680

PACKAGE DIMENSIONS

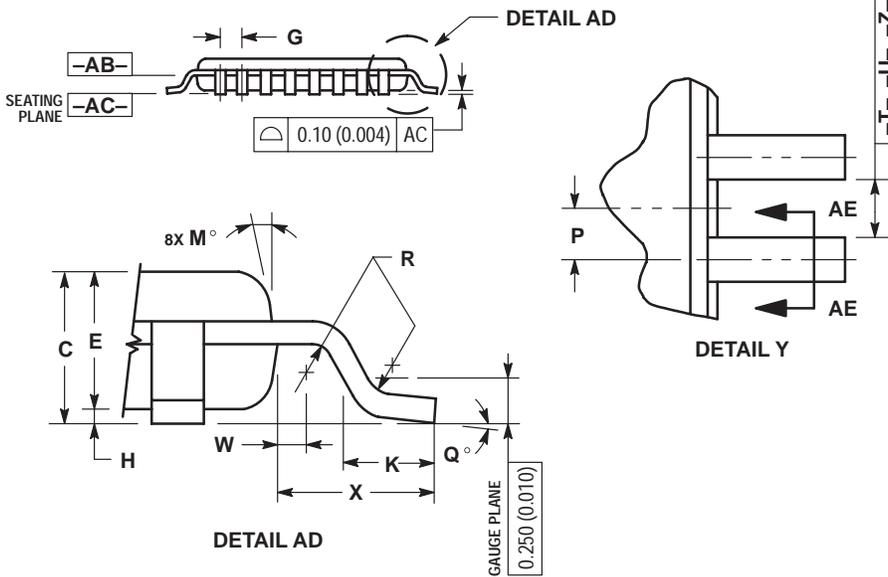
32-LEAD LQFP
PLASTIC PACKAGE
CASE 873A-02
ISSUE A



SECTION AE-AE

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DATUM PLANE -AB- IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
4. DATUMS -T-, -U-, AND -Z- TO BE DETERMINED AT DATUM PLANE -AB-.
5. DIMENSIONS S AND V TO BE DETERMINED AT SEATING PLANE -AC-.
6. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.250 (0.010) PER SIDE. DIMENSIONS A AND B DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -AB-.
7. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE D DIMENSION TO EXCEED 0.520 (0.020).
8. MINIMUM SOLDER PLATE THICKNESS SHALL BE 0.0076 (0.0003).
9. EXACT SHAPE OF EACH CORNER MAY VARY FROM DEPICTION.



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	7.000 BSC		0.276 BSC	
A1	3.500 BSC		0.138 BSC	
B	7.000 BSC		0.276 BSC	
B1	3.500 BSC		0.138 BSC	
C	1.400	1.600	0.055	0.063
D	0.300	0.450	0.012	0.018
E	1.350	1.450	0.053	0.057
F	0.300	0.400	0.012	0.016
G	0.800 BSC		0.031 BSC	
H	0.050	0.150	0.002	0.006
J	0.090	0.200	0.004	0.008
K	0.500	0.700	0.020	0.028
M	12° REF		12° REF	
N	0.090	0.160	0.004	0.006
P	0.400 BSC		0.016 BSC	
Q	1°	5°	1°	5°
R	0.150	0.250	0.006	0.010
S	9.000 BSC		0.354 BSC	
S1	4.500 BSC		0.177 BSC	
V	9.000 BSC		0.354 BSC	
V1	4.500 BSC		0.177 BSC	
W	0.200 REF		0.008 REF	
X	1.000 REF		0.039 REF	

Notes

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